

IN THE CLAIMS

Please cancel claim 1 without prejudice. Please add the following new claims:

Claims 1-22 (Canceled)

23. (New) A band-gap reference circuit having a plurality of possible operating states which respectively correspond to a plurality of possible values of a band-gap reference voltage, comprising:

a current source;

a circuit branch coupled to said current source for receiving current generated by said current source, said circuit branch including a resistor having a positive temperature coefficient connected in series with a base-emitter diode having a negative temperature coefficient, wherein said current develops a combined voltage across said series connection of said resistor and said base-emitter diode;

a further base-emitter diode;

an adjustment circuit having an output coupled to said current source and having inputs respectively coupled to said circuit branch and said further base-emitter diode for adjusting a band-gap reference voltage based on a said combined voltage and a base-emitter voltage of said further base-emitter diode; and

a start circuit having an output connected to one of said inputs of said adjustment circuit for preventing operation in one of said operating states.

24. (New) The band-gap reference circuit of Claim 23, wherein said start circuit is for injecting a current into the emitter of said further base-emitter diode.

25. (New) The band-gap reference circuit of Claim 24, wherein said start circuit has an output connected to said output of said adjustment circuit for applying a bias voltage to said output of said adjustment circuit.

26. (New) The band-gap reference circuit of Claim 23, wherein said start circuit has an output connected to said output of said adjustment circuit for applying a bias voltage to said output of said adjustment circuit.

27. (New) The band-gap reference circuit of Claim 23, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

28. (New) A band-gap reference circuit, comprising:
a current source for generating a current, said current source normally requiring a response time to transition from a first operating state thereof wherein said current source actively generates no current to a second operating state thereof wherein said current source actively generates said current;

a circuit branch coupled to said current source for receiving current generated by said current source, said circuit branch including a resistor having a positive temperature coefficient connected in

series with a base-emitter diode having a negative temperature coefficient, wherein said received current develops a combined voltage across said series connection of said resistor and said base-emitter diode;

a further base-emitter diode;

an adjustment circuit having an output coupled to said current source and having inputs respectively coupled to said circuit branch and said further base-emitter diode for adjusting a band-gap reference voltage based on a said combined voltage and a base-emitter voltage of said further base-emitter diode; and

a start circuit having an output coupled to said output of said adjustment circuit for reducing said response time.

29. (New) The band-gap reference circuit of Claim 28, wherein said start circuit is for applying a bias voltage to said output of said adjustment circuit.

30. (New) The band-gap reference circuit of Claim 29, wherein said start circuit has an output connected to said further base-emitter diode for injecting a current into the emitter of said further base-emitter diode.

31. (New) The band-gap reference circuit of Claim 28, wherein said start circuit has an output connected to said further base-emitter diode for injecting a current into the emitter of said further base-emitter diode.

32. (New) The band-gap reference circuit of Claim 28, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

33. (New) The band-gap reference circuit of Claim 28, wherein said band-gap reference circuit has a plurality of possible operating states which respectively correspond to a plurality of possible values of said band-gap reference voltage, and wherein said start circuit is coupled to said adjustment circuit and cooperable therewith for preventing operation in one of said operating states.

34. (New) The band-gap reference circuit of Claim 33, wherein said start circuit is for injecting a current into the emitter of said further base-emitter diode.

35. (New) The band-gap reference circuit of Claim 34, wherein said start circuit is for applying a bias voltage to said output of said adjustment circuit.

36. (New) The band-gap reference circuit of Claim 33, wherein said start circuit is for applying a bias voltage to said output of said adjustment circuit.

37. (New) The band-gap reference circuit of Claim 33, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

38. (New) A cellular telephone, comprising:

a voltage regulator capable of generating a regulated output voltage;

analog-to-digital circuitry capable of converting analog signals into digital signals; and

a band-gap reference circuit coupled to said voltage regulator and said analog-to-digital circuitry and capable of supplying a band-gap reference voltage to said voltage regulator and said analog-to-digital circuitry, wherein said band-gap reference voltage is relatively constant across an operating temperature range, said band-gap reference circuit having a plurality of possible operating states which respectively correspond to a plurality of possible values of said band-gap reference voltage, said band-gap reference circuit including a current source, a circuit branch coupled to said current source for receiving current generated by said current source, said circuit branch including a resistor having a positive temperature coefficient connected in series with a base-emitter diode having a negative temperature coefficient, wherein said current develops in said circuit branch a combined voltage across said series connection of said resistor and said base-emitter diode, a further base-emitter diode, an adjustment circuit having an output coupled to said current source and having inputs respectively coupled to said circuit branch and said further base-emitter diode for adjusting a band-gap reference voltage based on a said combined voltage and a base-emitter voltage of said further base-emitter diode, and a start circuit having an output connected to one of said inputs of said adjustment circuit for preventing operation in one of said operating states.

39. (New) The cellular telephone of Claim 38, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said

band-gap reference voltage caused by said further base-emitter diode.

40. (New) A cellular telephone, comprising:

a voltage regulator capable of generating a regulated output voltage;

analog-to-digital circuitry capable of converting analog signals into digital signals; and

a band-gap reference circuit coupled to said voltage regulator and said analog-to-digital circuitry and capable of supplying a band-reference voltage to said voltage regulator and said analog-to-digital circuitry wherein said band-gap reference voltage is relatively constant across an operating temperature range, said band-gap reference circuit including a current source for generating a current, said current source normally requiring a response time to transition from a first operating state thereof wherein said current source actively generates no current to a second operating state thereof wherein said current source actively generates said current, a circuit branch coupled to said current source for receiving current generated by said current source, said circuit branch including a resistor having a positive temperature coefficient connected in series with a base-emitter diode having a negative temperature coefficient, wherein said received current develops in said circuit branch a combined voltage across said series connection of said resistor and said base-emitter diode, a further base-emitter diode, an adjustment circuit having an output coupled to said current source and having inputs respectively coupled to said circuit branch and said further base-emitter diode for adjusting a band-gap reference voltage based on a said combined voltage and a base-emitter voltage of said further base-emitter diode, and a start circuit having an output coupled to said output of said adjustment circuit for reducing said response time.

41. (New) The band-gap reference circuit of Claim 40, wherein said band-gap reference circuit has a plurality of possible operating states which respectively correspond to a plurality of possible values of said band-gap reference voltage, and wherein said start circuit is coupled to said adjustment circuit and cooperable therewith for preventing operation in one of said operating states.

42. (New) The band-gap reference circuit of Claim 41, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

43. (New) The cellular telephone of Claim 40, including a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

44. (New) A band-gap reference circuit comprising:
a current source;
a circuit branch coupled to said current source for receiving current generated by said current source, said circuit branch including a resistor having a positive temperature coefficient connected in series with a base-emitter diode having a negative temperature coefficient, wherein said current develops a combined voltage across said series connection of said resistor and said base-emitter diode;
a further base-emitter diode;

an adjustment circuit for adjusting a band-gap reference voltage based on said combined voltage and a base-emitter voltage of said further base-emitter diode; and

a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.

45. (New) A cellular telephone, comprising:

a voltage regulator capable of generating a regulated output voltage;

analog-to-digital circuitry capable of converting analog signals into digital signals; and

a band-gap reference circuit coupled to said voltage regulator and said analog-to-digital circuitry and capable of supplying a band-gap reference voltage to said voltage regulator and said analog-to-digital circuitry, wherein said band-gap reference voltage is relatively constant across an operating temperature range, said band-gap reference circuit including a current source, a circuit branch coupled to said current source for receiving current generated by said current source, said circuit branch including a resistor having a positive temperature coefficient connected in series with a base-emitter diode having a negative temperature coefficient, wherein said current develops in said circuit branch a combined voltage across said series connection of said resistor and said base-emitter diode, a further base-emitter diode, an adjustment circuit for adjusting a band-gap reference voltage based on said combined voltage and a base-emitter voltage of said further base-emitter diode, and a correction circuit coupled to said adjustment circuit and cooperable therewith for at least partially offsetting a drop-off in said band-gap reference voltage caused by said further base-emitter diode.